## NSN 5962-01-111-7477

Memory Microcircuit - Page 1 of 1



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Features Provided:
Monolithic and programmable and 3-state output
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
9 input
Terminal Surface Treatment:
Solder
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
05869-726009-1 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
Yes - demil/mli
Fiig:
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